Journal of Materials Chemistry C

Materials for optical, magnetic and electronic devices

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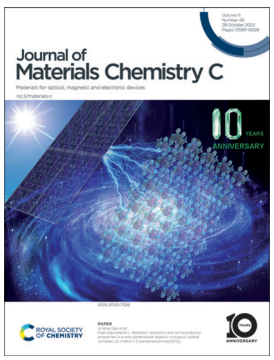

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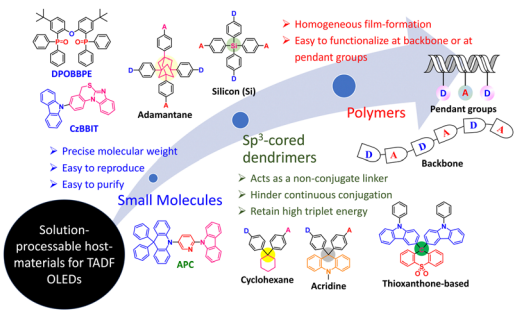

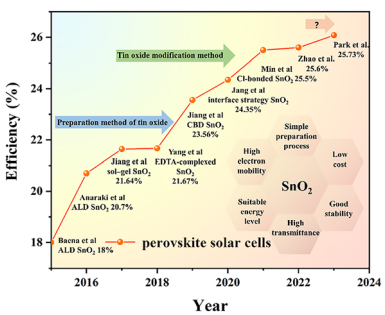

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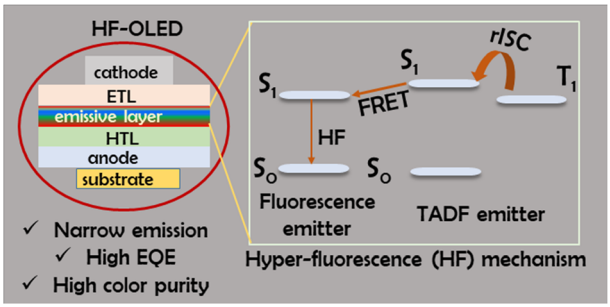

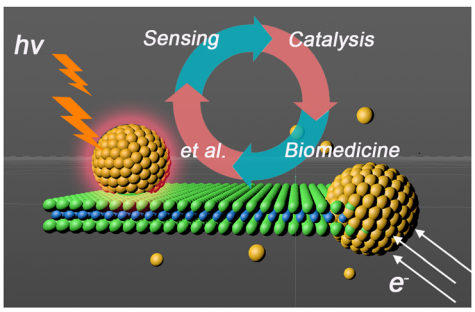

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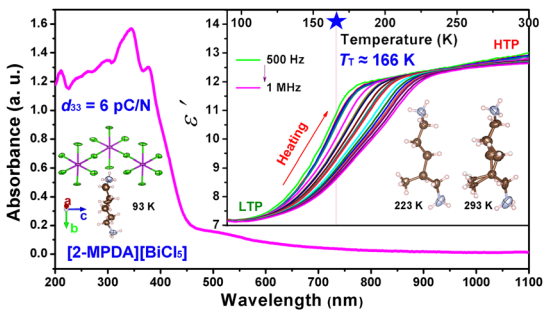

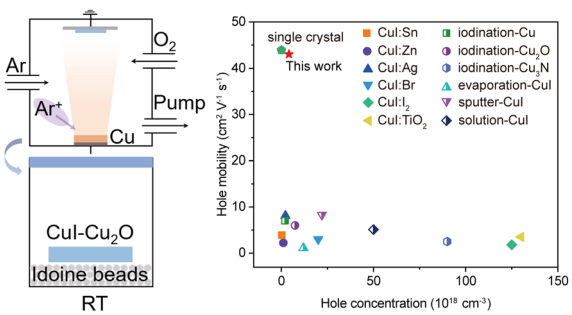

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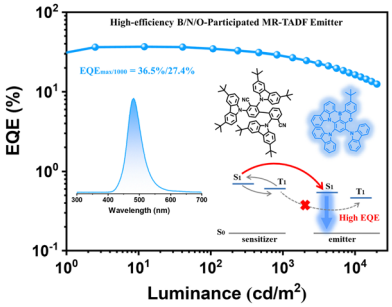

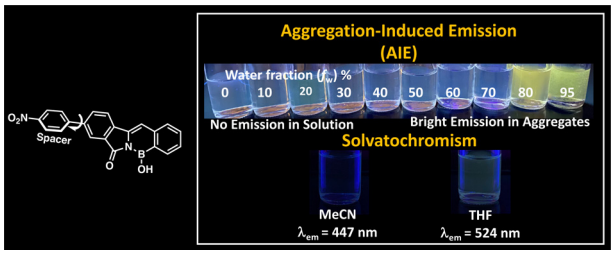

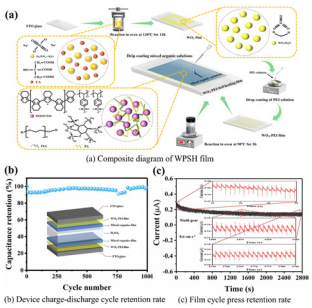

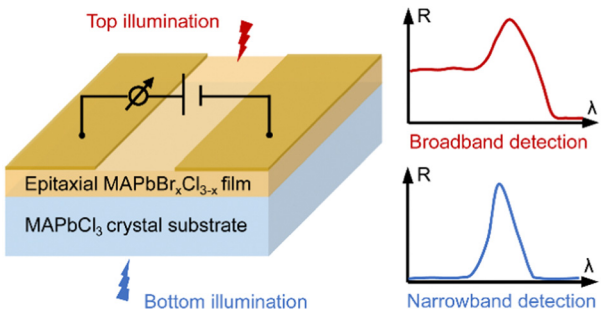

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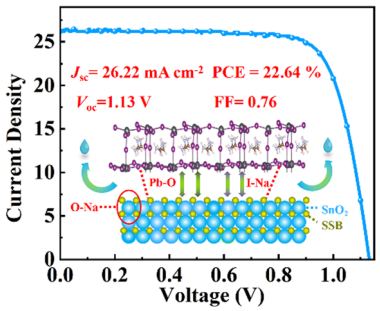

Small molecule-incorporated SnO_2 layer for efficient perovskite solar cells

Xin Zhou, Rui Kong, Rong Liu,* Ying Liu,* Mao Liang,* Zhitao Shen, Fumin Li, Mengqi Jin, Dong Yang, Shengmin Wang, Huilin Li, Ruirui Cao and Chong Chen*

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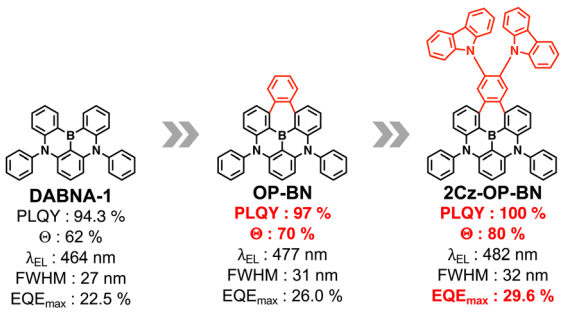

Phenylene-bridged cyclic multi-resonance TADF emitters for high-efficiency and high-color-purity sky-blue OLEDs with EQE of 30%

Kengo Kumada, Hisahiro Sasabe,* Misaki Matsuya, Naoto Yoshida, Keigo Hoshi, Takeru Nakamura, Haruki Nemma and Junji Kido*

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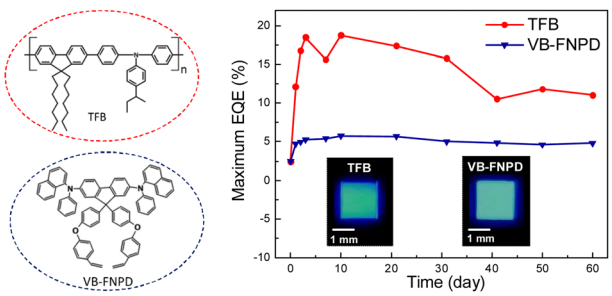

Long-term spontaneous negative aging behavior of encapsulated blue quantum dot light emitting devices: the influence of the hole transport material

Junfei Chen,* Atefeh Ghorbani, Fatemeh Samaeifar, Peter Chun, Quan Lyu, Giovanni Cotella, Dandan Song, Zheng Xu and Hany Aziz

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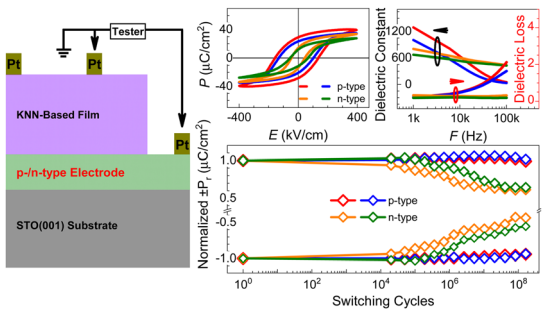

Buffer electrode layers tuned electrical properties, fatigue behavior and phase transition of KNN-based lead-free ferroelectric films

Liqiang Xu, Beibei Zhu, Song Dai, Kun Han, Pingfan Chen, Ke Wang, Zhen Huang,* Wenbin Wu and Feng Chen*

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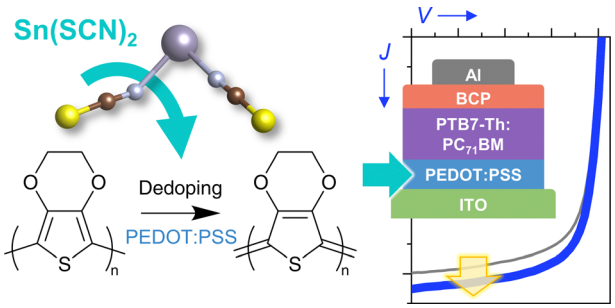

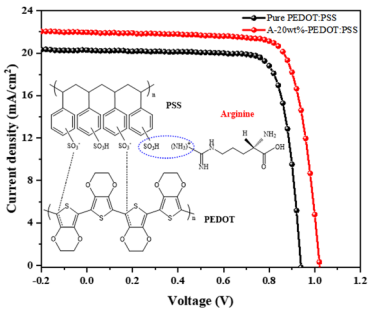

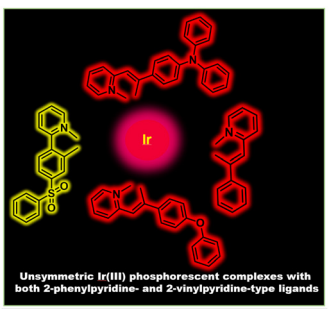

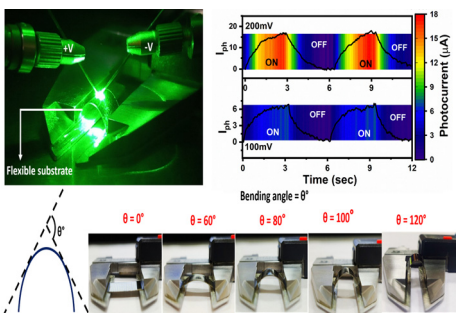

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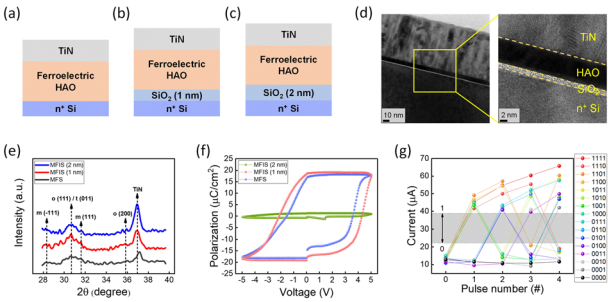
Effect of interfacial SiO_2 layer thickness on the memory performances in the $HfAlO_x$-based ferroelectric tunnel junction for a neuromorphic system

Yongjin Park, Jihyung Kim, Sunghun Kim, Dahye Kim, Wonbo Shim* and Sungjun Kim*



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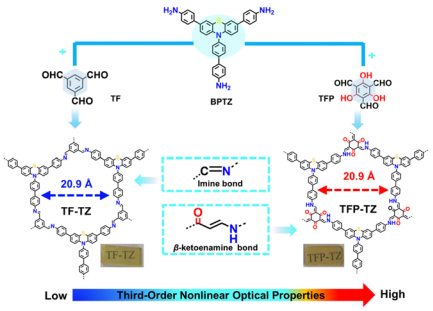
Phenothiazine-based donor–acceptor covalent–organic frameworks with keto–enol irreversible tautomerism as a promising third-order nonlinear optics material

Mingyan Li, Tingting Li, Chengtao Gong, Debo Ding, Jiawei Du, Xiangxiang Zhou, Yinglin Song, Yun-Fang Yang, Yuanbin She* and Jianhong Jia*



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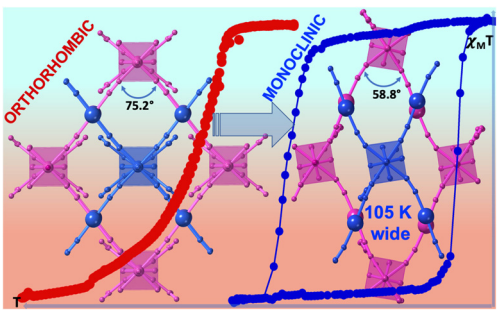
Guest-controlled polymorphism and exceptionally marked bi-stability in a spin crossover 3D porous amino-functionalized coordination polymer

Alejandro Orellana-Silla, Manuel Meneses-Sánchez, Rubén Turo-Cortés, Víctor Rubio-Giménez, Giel Arnauts, M. Carmen Muñoz, Rob Ameloot, Carlos Bartual-Murgui* and José Antonio Real*



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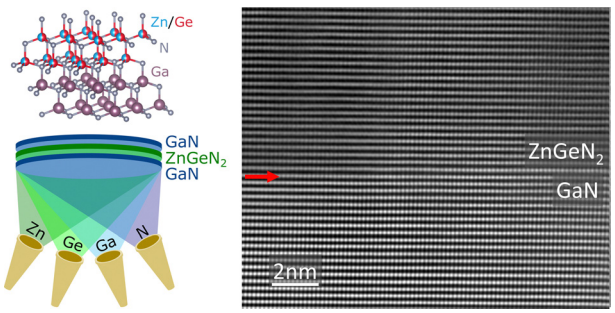
Structure, defects, and optical properties of commensurate GaN/$ZnGeN_2$/GaN double heterojunctions

M. Brooks Tellekamp,* M. K. Miller, Lin Zhou and Adele Tamboli



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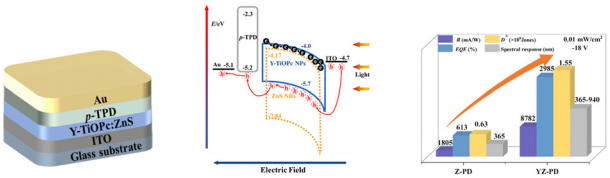

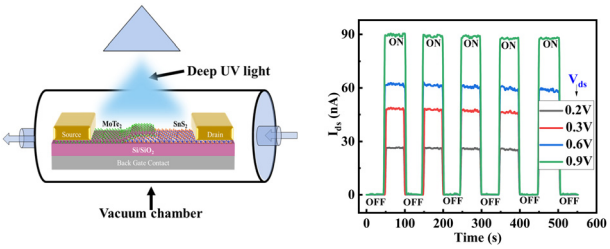

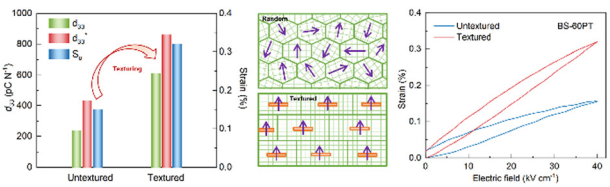

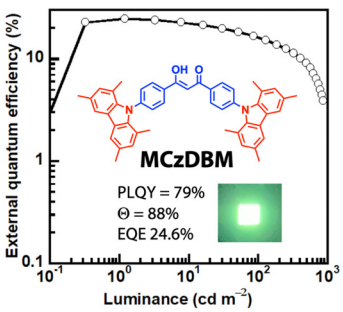

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